

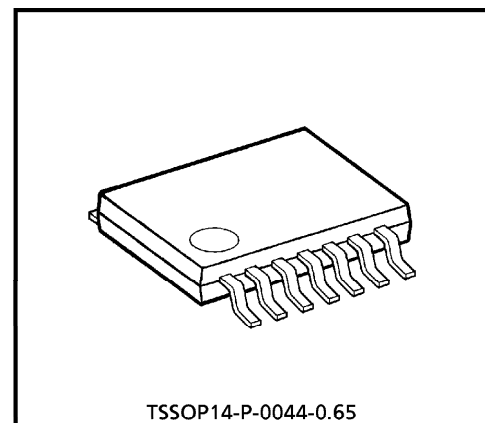
TC74VCX86FT

LOW-VOLTAGE QUAD EXCLUSIVE OR GATE WITH 3.6V TOLERANT INPUTS AND OUTPUTS

The TC74VCX86FT is a high performance CMOS EXCLUSIVE OR GATE. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. It is also designed with over voltage tolerant inputs and outputs up to 3.6V. All inputs are equipped with protection circuits against static discharge.

FEATURES

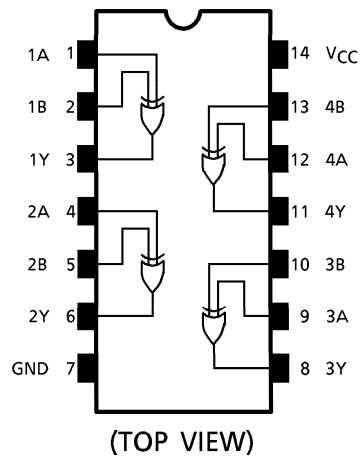
- Low Voltage Operation : $V_{CC} = 1.8 \sim 3.6V$
- High Speed Operation : $t_{pd} = TBD$ (max.) at $V_{CC} = 3.0 \sim 3.6V$
 $t_{pd} = TBD$ (max.) at $V_{CC} = 2.3 \sim 2.7V$
 $t_{pd} = TBD$ (max.) at $V_{CC} = 1.8V$
- 3.6V Tolerant inputs and outputs.
- Output Current : $I_{OH}/I_{OL} = \pm 24mA$ (min.) at $V_{CC} = 3.0V$
 $I_{OH}/I_{OL} = \pm 18mA$ (min.) at $V_{CC} = 2.3V$
 $I_{OH}/I_{OL} = \pm 6mA$ (min.) at $V_{CC} = 1.8V$
- Latch-up Performance : $\pm 300mA$
- ESD Performance : Human Body Model $> \pm 2000V$
Machine Model $> \pm 200V$
- Package : TSSOP
(Thin Shrink Small Outline Package)
- Power Down Protection is provided on all inputs and outputs.



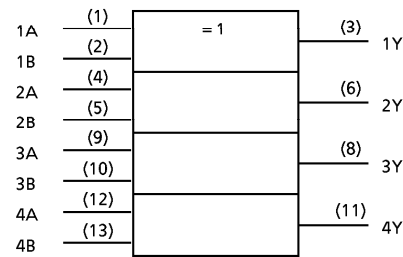
Weight : 0.06g (Typ.)

PRELIMINARY

PIN ASSIGNMENT



IEC LOGIC SYMBOL



TRUTH TABLE

INPUTS		OUTPUTS
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

PRELIMINARY

MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	V_{CC}	- 0.5~4.6	V
DC Input Voltage	V_{IN}	- 0.5~4.6	V
DC Output Voltage	V_{OUT}	- 0.5~4.6 (Note 1)	V
		- 0.5~ V_{CC} + 0.5 (Note 2)	
Input Diode Current	I_{IK}	- 50	mA
Output Diode Current	I_{OK}	$\pm$ 50 (Note 3)	mA
DC Output Current	I_{OUT}	$\pm$ 50	mA
Power Dissipation	P_D	180	mW
DC V_{CC} / Ground Current	I_{CC} / I_{GND}	$\pm$ 100	mA
Storage Temperature	T_{stg}	- 65~150	$^{\circ}$ C

- (Note 1) V_{CC} = 0V
- (Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.
- (Note 3) V_{OUT} < GND, V_{OUT} > V_{CC}

RECOMMENDED OPERATING RANGE

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	V_{IN}	-0.3~3.6	V
Output Voltage	V_{OUT}	0~3.6 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH}/I_{OL}	± 24 (Note 7)	mA
		± 18 (Note 8)	
		± 6 (Note 9)	
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 10)	ns/V

(Note 4) Data Retention Only

(Note 5) $V_{CC} = 0V$

(Note 6) High or Low State

(Note 7) $V_{CC} = 3.0\sim 3.6V$ (Note 8) $V_{CC} = 2.3\sim 2.7V$ (Note 9) $V_{CC} = 1.8V$ (Note 10) $V_{IN} = 0.8\sim 2.0V$, $V_{CC} = 3.0V$

PRELIMINARY

ELECTRICAL CHARACTERISTICS

DC characteristics ($T_a = -40\sim 85^\circ\text{C}$, $2.7V < V_{CC} \leq 3.6V$)

PARAMETER		SYMBOL	TEST CONDITION		V _{CC} (V)	MIN.	MAX.	UNIT
Input Voltage	“H” Level	V _{IH}			2.7~3.6	2.0	—	V
	“L” Level	V _{IL}			2.7~3.6	—	0.8	
Output Voltage	“H” Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = - 100μA	2.7~3.6	V _{CC} - 0.2	—	V
				I _{OH} = - 12mA	2.7	2.2	—	
				I _{OH} = - 18mA	3.0	2.4	—	
				I _{OH} = - 24mA	3.0	2.2	—	
	“L” Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100μA	2.7~3.6	—	0.2	
				I _{OL} = 12mA	2.7	—	0.4	
				I _{OL} = 18mA	3.0	—	0.4	
				I _{OL} = 24mA	3.0	—	0.55	
Input Leakage Current		I _{IN}	V _{IN} = 0~3.6V		2.7~3.6	—	± 5.0	μA
Power Off Leakage Current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6V		0	—	10.0	μA
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND		2.7~3.6	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6V		2.7~3.6	—	± 20.0	
Increase In I _{CC} Per Input		ΔI _{CC}	V _{IH} = V _{CC} - 0.6V		2.7~3.6	—	750	μA

ELECTRICAL CHARACTERISTICSDC characteristics ($T_a = -40 \sim 85^\circ\text{C}$, $2.3\text{V} \leq V_{CC} \leq 2.7\text{V}$)

PARAMETER		SYMBOL	TEST CONDITION			V _{CC} (V)	MIN.	MAX.	UNIT
Input Voltage	“H” Level	V _{IH}				2.3~2.7	1.6	—	V
	“L” Level	V _{IL}				2.3~2.7	—	0.7	
Output Voltage	“H” Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = - 100μA	2.3~2.7	V _{CC} - 0.2	—	V	
				I _{OH} = - 6mA	2.3	2.0	—		
				I _{OH} = - 12mA	2.3	1.8	—		
				I _{OH} = - 18mA	2.3	1.7	—		
	“L” Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100μA	2.3~2.7	—	0.2		
				I _{OL} = 12mA	2.3	—	0.4		
				I _{OL} = 18mA	2.3	—	0.6		
Input Leakage Current		I _{IIN}	V _{IN} = 0~3.6V	2.3~2.7	—	± 5.0	μA		
Power Off Leakage Current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6V	0	—	10.0	μA		
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND	2.3~2.7	—	20.0	μA		
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6V _{CC}	2.3~2.7	—	± 20.0			

PRELIMINARY

ELECTRICAL CHARACTERISTICS

DC characteristics (Ta = -40~85°C, 1.8V ≤ V_{CC} < 2.3V)

PARAMETER		SYMBOL	TEST CONDITION		V _{CC} (V)	MIN.	MAX.	UNIT
Input Voltage	“H” Level	V _{IH}			1.8~2.3	0.7 × V _{CC}	—	V
	“L” Level	V _{IL}			2.8~2.3	—	0.2 × V _{CC}	
Output Voltage	“H” Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = - 100μA	1.8	V _{CC} - 0.2	—	V
				I _{OH} = - 6mA	1.8	1.4	—	
	“L” Level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 100μA	1.8	—	0.2	
				I _{OL} = 6mA	1.8	—	0.3	
Input Leakage Current		I _{IIN}	V _{IN} = 0~3.6V		1.8	—	± 5.0	μA
Power Off Leakage Current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6V		0	—	10.0	μA
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND		1.8	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6V		1.8	—	± 20.0	

AC characteristics (Ta = -40~85°C, Input t_r = t_f = 2.0ns, C_L = 30pF, R_L = 500Ω)

PARAMETER		SYMBOL	TEST CONDITION		V _{CC} (V)	MIN.	MAX.	UNIT
Propagation Delay Time		t _{pLH} t _{pHL}	(Fig.1, 2)		1.8	1.5	TBD	ns
					2.5 ± 0.2	1.0	TBD	
					3.3 ± 0.3	0.8	TBD	
Output To Output Skew		t _{osL} t _{osHL}	(Note 11)		1.8	—	TBD	ns
					2.5 ± 0.2	—	TBD	
					3.3 ± 0.3	—	TBD	

For C_L = 50pF, add approximately 300ps to the AC maximum specification.

(Note 11) Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic switching characteristics (Ta = 25°C, Input $t_r = t_f = 2.0\text{ns}$, $C_L = 30\text{pF}$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	V _{IH} = 1.8V, V _{IL} = 0V (Note 12)	1.8	TBD	V
		V _{IH} = 2.5V, V _{IL} = 0V (Note 12)	2.5	TBD	
		V _{IH} = 3.3V, V _{IL} = 0V (Note 12)	3.3	TBD	
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	V _{IH} = 1.8V, V _{IL} = 0V (Note 12)	1.8	TBD	V
		V _{IH} = 2.5V, V _{IL} = 0V (Note 12)	2.5	TBD	
		V _{IH} = 3.3V, V _{IL} = 0V (Note 12)	3.3	TBD	
Quiet Output Minimum Dynamic V _{OH}	V _{OHV}	V _{IH} = 1.8V, V _{IL} = 0V (Note 12)	1.8	TBD	V
		V _{IH} = 2.5V, V _{IL} = 0V (Note 12)	2.5	TBD	
		V _{IH} = 3.3V, V _{IL} = 0V (Note 12)	3.3	TBD	

(Note 12) Parameter guaranteed by design.

Capacitive characteristics (Ta = 25°C)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	UNIT
Input Capacitance	C _{IN}	—	1.8, 2.5, 3.3	TBD	pF
Output Capacitance	C _{OUT}		0	TBD	pF
Power Dissipation Capacitance	C _{PD}	f _{IN} = 10MHz (Note 13)	1.8, 2.5, 3.3	TBD	pF

(Note 13) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

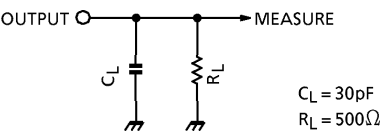
Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

PRELIMINARY

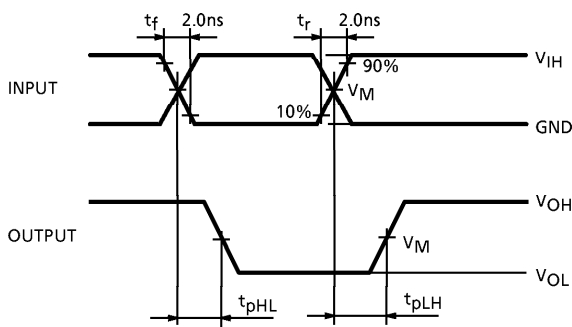
TEST CIRCUIT

Fig.1



AC WAVEFORM

Fig.2 t_{pLH} , t_{pHL}

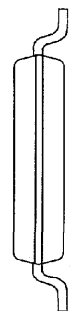
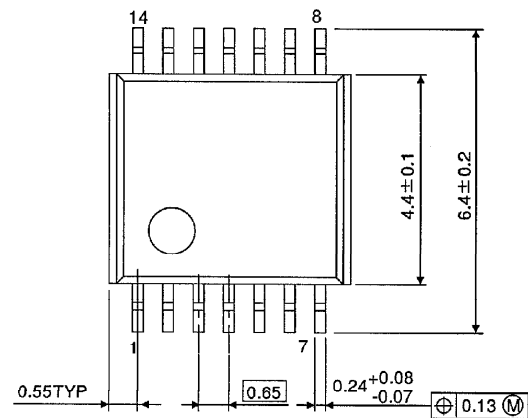


SYMBOL	V_{CC}		
	$3.3 \pm 0.3\text{V}$	$2.5 \pm 0.2\text{V}$	1.8V
V_{IH}	2.7V	V_{CC}	V_{CC}
V_M	1.5V	$V_{CC}/2$	$V_{CC}/2$

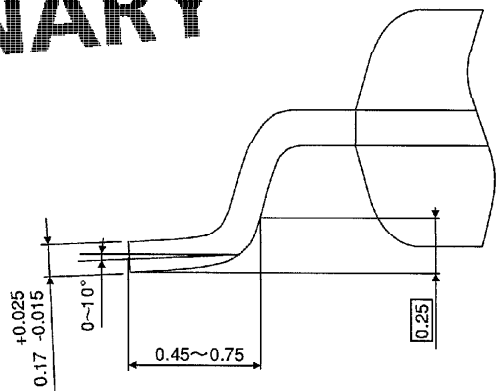
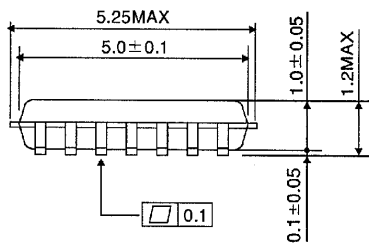
PRELIMINARY

PACKAGE DIMENSIONS
TSSOP14-P-0044-0.65

Unit : mm



PRELIMINARY



Weight : 0.06g (Typ.)

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